

# New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.  
SPRINGFIELD, NEW JERSEY 07081  
U.S.A.

TELEPHONE: (973) 376-2922  
(212) 227-6005  
FAX: (973) 376-8960

Standard tolerances are 5%  
20%, 10%, 2% and 1% are available

## 400 mW low voltage avalanche low noise silicon zener diodes

### FEATURES

- Controlled avalanche
- Voltages from 4.3 to 10 V
- Low reverse leakage
- Low noise
- Hermetically sealed glass package
- APD can select any voltage in tolerances 1%, 2%, 5% and 10% at your application's test current.

### MAXIMUM RATINGS

- Junction Temperature -65°C to +175°C
- Storage Temperature -65°C to +200°C
- DC Power Dissipation: 400mW @  $T_L = 50^\circ\text{C}$
- Derate above 50°C: 2.67mW/ $^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS @ 25°C

Type (1)	Nominal Zener Voltage @ $I_z$	Maximum Impedance (2)		Maximum Reverse Leakage		Maximum Noise Density @ 250 $\mu\text{A}$ (3)	Maximum Regulation
		$Z_z$	$I_z$	$I_{zV}$	$V_{dc}$		
		$\Omega$	mA	mA	Vdc	$\mu\text{V}/\text{Hz}$	
1N6082B	4.3	16	20	2.0	1.5	1	0.75
1N6083B	4.7	10	10	2.0	1	0.50	1.0
1N6084B	5.1	10	5	2.0	3.0	1	0.30
1N6085B	5.6	40	1	2.0	4.5	1	0.10
1N6086B	6.2	45	1	0.5	5.6	1	0.10
1N6087B	6.8	50	1	0.05	6.2	1	0.10
1N6088B	7.5	50	1	0.01	6.8	1	0.10
1N6089B	8.2	60	1	0.01	7.5	1	0.10
1N6090B	9.1	60	1	0.01	8.2	2	0.10
1N6091B	10.0	60	1	0.01	9.1	2	0.10

### MECHANICAL CHARACTERISTICS

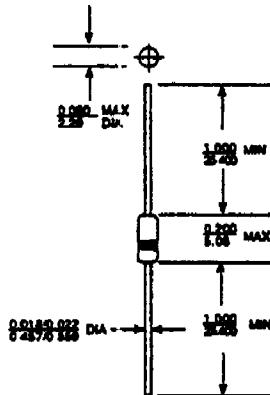


FIGURE 1 all dimensions in INCH mm

CASE: Hermetically sealed glass package (DO-35)

FINISH: Corrosion resistant. Leads are tin plated.

Thermal Resistance: 200°C/W junction to lead at 0.375-inches from body.

Polarity: Cathode banded.

WEIGHT: 0.2 grams (typ).

This series also available in DO-7 package. Consult factory for availability.

Note 1 The JEDEC type numbers shown with a B suffix have a  $\pm 5\%$  tolerance. No suffix indicates a  $\pm 20\%$  tolerance. Suffix A denotes a  $\pm 10\%$  tolerance, suffix C denotes a  $\pm 2\%$  tolerance and suffix D denotes  $\pm 1\%$  tolerance.

Note 2 The zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current ( $I_{zV}$ ) is superimposed on  $I_z$ .

Note 3 Measured from 1 KHz to 3 KHz in noise density measurement circuit shown on the following page.

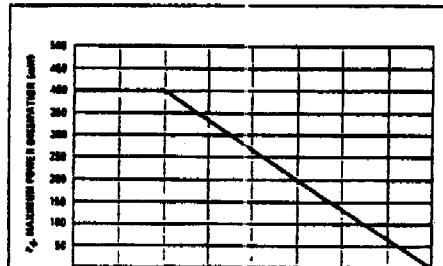


Figure 2 POWER DERATING

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